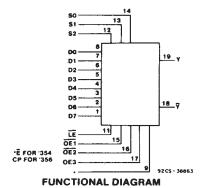
File Number 1690

CD54/74HC354, CD54/74HCT354 CD54/74HC356, CD54/74HCT356

Data sheet acquired from Harris Semiconductor SCHS277



High-Speed CMOS Logic

8-Input Multiplexer/Register, 3-State

CD54/74HC/HCT354 — Transparent Data & Select Latches CD54/74HC/HCT356 — Edge-Triggered Data Flip-Flops Transparent Select Latches

Type Features:

- Buffered inputs
- 3-State Complementary Outputs
- Bus Line Driving Capability
- Typical propagation delay: V_{CC} = 5V, C_L = 15 pF, T_A = 25°C Data to Output (354) = 18 ns Clock to Output (356) = 22 ns

The RCA-CD54/74HC/HCT354 and CD54/74HC/HCT356 are data selectors/multiplexers that select one of eight sources. In both the HC/HCT354 and HC/HCT356 the data select bits S0, S1, and S2 are stored in transparent latches that are enabled by a low latch enable input, $\overline{\text{LE}}$.

In the HC/HCT354 the data enable input, \overline{E} , controls transparent latches that pass data to the outputs when \overline{E} is high and latches in new data when \overline{E} is low.

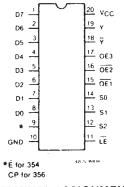
In the HC/HCT356 the data is stored in edge-triggered flipflops that are triggered by a low-to-high clock transition.

In both types the three-state outputs are controlled by three output-enable inputs $\overline{OE1}$, $\overline{OE2}$, and OE3.

The CD54HC/HCT354/356 are supplied in 20-lead ceramic dual-in-line packages (F suffix). The CD74HC/HCT354/356 are supplied in 20-lead plastic dual-in-line plastic packages (E suffix). The CD54/74HC/HCT354/356 are also supplied in chip form (H suffix). The CD74HC/HCT354/356 are also available in plastic surface mounted packages (M suffix).

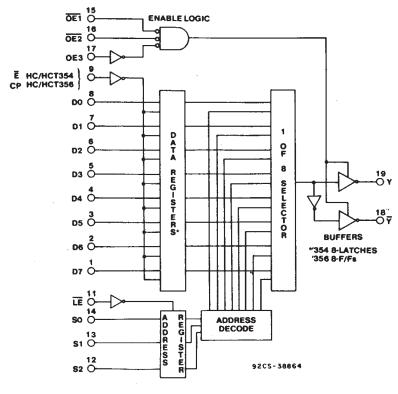
Family Features:

- Fanout (Over Temperature Range): Standard Outputs - 10 LSTTL Loads Bus Driver Outputs - 15 LSTTL Loads
- Wide Operating Temperature Range: CD74HC/HCT: -40 to +85°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- Alternate Source is Philips/Signetics
 CD54HC/CD74HC Types:
- 2 to 6 V Operation High Noise Immunity: $N_{tL} = 30\%$, $N_{H} = 30\%$ of V_{CC} ; @ $V_{CC} = 5$ V
- CD54HCT/CD74HCT Types: 4.5 to 5.5 V Operation Direct LSTTL Input Logic Compatibility V_{IL} = 0.8 V Max., V_{IH} = 2 V Min. CMOS Input Compatibility
 - $I_1 \leq 1 \ \mu A @ V_{OL}, V_{OH}$
 - I ST DA W VOL. VOH



TERMINAL ASSIGNMENT

This data sheet is applicable to the CD54HC354 and CD74HCT356. The CD54HCT354, CD54HCT356, CD74HC356, and CD54HCT356 were not acquired from Harris Semiconductor. See SCHS179 for information on the CD74HC354 and CD74HCT354.



Block Diagram

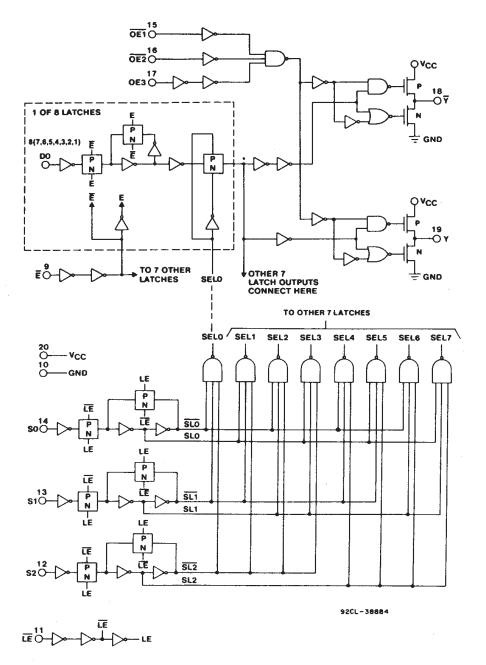
TRUTH TABLE

	Inputs									
s	elect	#	Enable Data 'HC354 'HCT354	Clock 'HC356 'HCT356	Output Enables		Out	outs		
S2	S1	S0	E	СР	OE1	ŌE2	OE3	Y	Y	
Х	Х	Х	X	Х	н	Х	Х	Z	Z	
х	Х	Х	X	X	X	н	х	Z	Z	
X	Х	Х	x	×	X	Х	L	Z	Z	
L	L	L	L	~	L	L	н	D0	D0	
L	L	L	н	HorL	L	L	н	D0 _n	D 0 _n	
L	L	н	L	~	L	L	н	D1	D1	
L	L	н	н	HorL	L	. L	н	D1,	D1,	
L	н	L	L	~	L	L	н	D2	D2	
L	н	L	н	HorL	L	L	н	D2 _n	D2 _n	
L	н	н	L	~	L	L	н	D3	D3	
L	н	- F1	н	HorL	L	Ł	н	D3,	D3 _n	
н	L	L	L	1	L	Ĺ	н	D4	D4	
н	L	L	н	HorL	L	Ł	н	D4 _n	D4 _n	
н	L	н	L	1	L	٤	н	D5	D5	
н	L	н	н	HorL	L	L	н	D5,	D5,	
н	н	L	L		L	Ł	н	D6	D6	
н	н	L	н	HorL	L	L	н	D6,	D6,	
н	н	н	L.	1	L	L	H	07	D7	
н	∘H,	н	н	HorL	L	L	н	D7,	D7.	

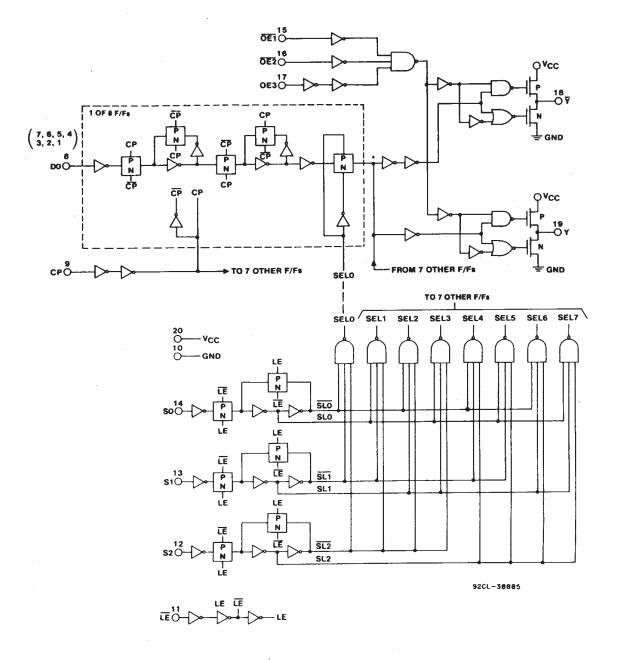
- Notes H = high level (steady state) L = low level (steady state)

- respectively, at the time of the low-to-high clock transition in the case of HC356
- D0_n... D7_n = the level of steady state inputs D0 through D7, respectively, before the most recent low-to-high transition of data control or clock

This column shows the input address setup with LE low



HC/HCT354 Logic Diagram



HC/HCT356 Logic Diagram

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE, (Vcc)	
(Voltages referenced to ground)	-0.5 to +7V
DC INPUT DIODE CURRENT, $I_{\rm IK}$ (FOR V, $<$ -0.5 V OR V, $>$ V_{cc} + 0.5V)	
DC OUTPUT DIODE CURRENT, Iok (FOR V, < -0.5 V OR V, > 0.5 V +V _{cc})	
DC DRAIN CURRENT, PER OUTPUT (Io) (FOR -0.5 V < Vo < Vcc + 0.5V)	
DC Vcc OR GROUND CURRENT (lcc)	
POWER DISSIPATION PER PACKAGE (Pp):	2
For T _A = -40 to +60°C (PACKAGE TYPE E)	
For T _A = +60 to +85°C (PACKAGE TYPE E)	
For T _A = -55 to +100°C (PACKAGE TYPE F, H)	
For T _A = +100 to +125°C (PACKAGE TYPE F, H)	
For T _A = -40 to +70° C (PACKAGE TYPE M)	
For T _A = +70 to +125°C (PACKAGE TYPE M)	Derate Linearly at 6 mW/°C to 70 mW
OPERATING-TEMPERATURE RANGE (T _A):	
PACKAGE TYPE F, H	
PACKAGE TYPE E, M	
STORAGE TEMPERATURE (Tstg)	
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 \pm 1/32 in. (1.59 \pm 0.79 mm) from case for 10 s max.	
Unit inserted into a PC Board (min. thickness 1/16 in., 1.59 mm)	
with solder contacting lead tips only	

RECOMMENDED OPERATING CONDITIONS:

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges: . .

CHARACTERISTIC	LIN	IITS	1141170
	MIN.	MAX.	
Supply-Voltage Range (For T _A = Full Package Temperature Range)		1	1
CD54/74HC Types	2	6	
CD54/74HCT Types	4.5	5.5	V V
DC Input or Output Voltage V _I , V _o	0	V _{cc}	V V
Operating Temperature T _A :		· · · · · · · · · · · · · · · · · · ·	1
CD74 Types	-40	+85	°C
CD54 Types	-55	+125	
Input Rise and Fall Times t _n t _f			
at 2 V	0	1000	
at 4.5 V	Ŏ	500	ns
at 6 V	0	400	1

*Unless otherwise specified, all voltages are referenced to Ground.

STATIC ELECTRICAL CHARACTERISTICS

		CD74	HC35	4/356/	CD54	HC35	i4/356	;			CD74HCT354/356/CD54HCT354/356									
		TEST CONDITIONS			74HC/54HC 74HC TYPE TYPE		541 TY		TEST		1	CT/54 TYPE		74НСТ ТҮРЕ		54НСТ ТУРЕ				
CHARACTERISTIC	V ,	I _o			25° C	;	-4 +85	0/ i° C	-5 +12		V,	Vcc		•25° C	;	1	0/ 5°C	1 .	5/ 5°C	UNITS
	v	mA	V	Min	Тур	Max	Min	Max	Min	Max	v	v	Min	Тур	Max	Min	Max	Min	Max	
High-Level			2	1.5			1.5	—	1.5	—		4.5								
Input Voltage V _{IH}		1	4.5	3.15	-	-	3.15	_	3.15		-	to	2	-	–	2	-	2	-	v
			6	4.2	_		4.2	-	4.2	-		5.5								
Low-Level			2		-	0.5	-	0.5		0.5		4.5								
Input Voltage V _{IL}			4.5	-	-	1.35	-	1.35	-	1.35	-	to	-		0.8	-	0.8	-	0.8	v
			6	-	—	1.8	-	1.8	-	1.8		5.5								
High-Level	V _H		2	1.9	-	-	1.9	_	1.9	-	٧ _u									
Output Voltage Vон	or	-0.02	4.5	4.4			4.4	-	4.4		or	4.5	4.4	-	-	4.4	-	4.4	-	v
CMOS Loads	V _{iet}		6	5.9			5.9	_	5.9		Vin									
	Vu										V _{it}									
TTL Loads	or	-6	4.5	3.98		-	3.84		3.7	-	or	4.5	3.98		-	3.84	-	3.7	-	v
(Bus Driver)	Viiii	-7.8	6	5.48	-	-	5.34	-	5.2	-	Vet									
Low-Level	۷ _u		2	-	_	0.1	-	0.1	-	0.1	V _{it}]	
Output Voltage Vol.	or	0.02	4.5			0.1	-	0.1	-	0.1	or	4.5	-	-	0.1	-	0.1		0.1	v
CMOS Loads	Vet]	6	-	_	0.1	-	0.1		0.1	Viti									
	۷۰	1									Vic									
TTL Loads	or	6	4.5	-	-	0.26	-	0.33	-	0.4	or	4.5	-	-	0.26	-	0.33	-	0.4	v
(Bus Driver)	ViH	7.8	6	-		0.26	- 1	0.33	-	0.4	V _{et}									
Input Leakage	V _{cc}	[Any									
Current I	or		6	_		±0.1	_	±1	_	±1	Voltage Between	5.5	-	-	±0.1		±1	-	±1	μA
	Gnd										V _{cc} & Gnd									
Quiescent	V _{cc}	1									Vcc	<u> </u>								
Device	or	0	6	_	_	8	-	80	-	160	or	5.5	-	_	8		80	-	160	μA
Current Icc.	Gnd										Gnd									
Additional Quiescent Device Current per input pin: 1 unit load Δ lcc*								-			V _{cc} -2.1	4.5 to 5.5	_	100	360	_	450		490	μA
3-State Leakage Current loz	V _{IL} Or V _{#4}	V _o = V _{CC} Or Gnd	6	-	_	<u>+</u> 0.5	-	±5.0		<u>±</u> 10	V _n or V _{in}	5.5	-	-	<u>+</u> 0.5		±5.0		±10	μA

*For dual-supply systems theoretical worst case (V₁ = 2.4 V, V_{cc} = 5.5 V) specification is 1.8 mA.

HCT354 Input Loading Table

Input	Unit Loads*
D0-D7	0.50
S0, S1, S3	0.70
OE1, OE2	0.80
OE3	0.25
<u>L</u> E	0.25
Ē	0.60

*Unit Load is ΔI_{CC} limit specified in Static Characteristic Chart, e.g., 360 μ A max. @ 25°C.

HCT356 Input Loading Table

Input	Unit Loads*
D0-D7	0.50
S0, S1, S3	0.70
OE1, OE2	0.80
OE3	0.25
LE	0.25
CP	0.60

*Unit Load is ΔI_{cc} limit specified in Static Characteristic Chart, e.g., 360 μ A max. @ 25°C.

SWITCHING CHARACTERISTICS (Vcc = 5 V, TA = 25°C, input tr, tr = 6 ns) - HC/HCT354

CHARACTERISTIC	CL	SYMBOL	ТҮР	ICAL	UNITS
	(pF)	STMOUL	54/74HC	54/74HCT	UNITS
Propagation Delay Dn → Y, Y	15	t _{PLH} , t _{PHL}	18	20	ns
Ē → Y, Ÿ	15	t _{PLH} , t _{PHL}	21	23	ns
Sn→ Y, Ÿ	15	telh, tehl	22	25	ns
$\overline{\text{LE}} \rightarrow Y, \overline{Y}$	15	tplh, tphl	24	25	ns
Output Disabling Time	15	t _{PLZ} , t _{PHZ}	13	13, 16	ns
Output Enabling Time	15	tezl, tezh	12, 13	14	ns
Power Dissipation Capacitance*	_	CPD	90	92	рF

*CPD is used to determine the dynamic power consumption, per device.

 P_{D} =V_{\text{CC}}^{2} f_{i} \left(C_{\text{PD}} + C_{\text{L}} \right) where:

f_i = input frequency,

CL = output load capacitance.

V_{cc} = supply voltage

PREREQUISITE FOR SWITCHING FUNCTION - HC/HCT354

				25	°C		-4	0°C te	o +85°	°C	-5	5°C to	+125	°C	
CHARACTERISTIC	SYMBOL	Vcc	H	IC	H	СТ	74	нс	741	ICT	54	HC	54H	ICT	UNITS
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
E pulse width		2	80	—	—		100	-	-	-	120	-	—	-	
	t _{PLH}	4.5	16	-	16	-	20	—	20		24	-	24	-	ns
	t _{PHL}	6	14	-	_		17	—	_		20	_	-		
LE pulse width		2	80	-	—	-	100	-			120	-	-	-	
	t _{PLH}	4.5	16	-	16		20	-	20	_	24	_	24	-	ns
	t _{PHL}	6	14	-		_	17				20	-	[
Set Up Times		2	50	-	—	-	65	—	-	-	75	—		-	
Dn 🛨 Ē	tsu	4.5	10	_	10	_	13		13	-	15	_	15	_	ns
		6	9	_			11	-	—	-	13	_	_	-	
		2	50	-		—	65		_	-	75	—	—	-	
Sn 🔶 LE	tsu	4.5	10	-	10	-	13	-	13	—	15		15	-	ns
		6	9	_		_	11			_	13	_	-	-	
Hold Times		2	45	_	_		55	-	—	_	70				
Dn→Ē	tн	4.5	9		9		11	—	11	—	14		14		ns
		6	8				9			_	12	_	_		
		2	45	—	_	—	55	-		-	70	—	—	_	
Sn → LE	ŧн	4.5	9	—	9		11		11.		14		14	-	ns
		6	8	—			9	-	—		12		_		

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SWITCHING CHARACTERISTICS (CL = 50 pF, Input t, t = 6 ns) - HC/HCT354

 $(k_{i})_{i\in \mathbb{N}}$

SYMBOL	Vcc	H												
			C			74	IC	ICT	54HCT		UNITS			
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t _{PLH}	2	-	210				265		-		315	-	-	
T PHL	4.5	_	42		47	—	53		59		63	-	71	ns
	6	_	36	_			45	_	—		54			
	2	-	250				315	-	[_]		375	-	-	
	4.5		50		54	-	63	_	68		75	-	81	กร
t _{PHL}	6	-	43				54				64	—		
	2	1 -	260			-	325		-		390	-	-	
	4.5	-	52	_	59	-	65	-	74	-	78	-	89	ns
t _{PHL}	6	-	44	-		—	55				66			L
	2		290		_	-	365	-	-			-		
	4.5	-	58	-	63		73	-	79	-		-	94	ns
L PHL	6	-	49	<u> </u>	-		62		<u> </u>					
	2	-	155	-	-	-	195	-	-	-	1	-	-	
	4.5		31	_	33	-	39		41	-		-	50	
t _{PLZ}	6	_	26			1 -	33_	-	-					ns
tou z	2	-	155	<u> </u>	[_		195		-		3	-	-	
(PHZ	4.5	_	31	_	39	-	39	_	49	-		-	59	
	6	-	26	_			33	<u> </u>	-			1 -		Ļ
	2		150		—	_	190	- 1	-	-	225		-	
	4.5	-	30	-	34		38	-	43	-	45	-	51	
t _{PZL}	6		26	_	_	_	33	-	-		38			ns
toru	2	- 1	160	-	-	-	200	-	-	-	240		-	
*PZH	4.5	-	32	-	34	-	40	-	43	-	48	-	51	
	6	} _	27	-	-	-	34	_			41		<u> </u>	
	2	- 1	60	-	1-		75	-	-	-	90	-	-	
t _{TLH}	4.5		12	-	12	-	15	-	15	-	18	-	18	ns
t _{THL}	6	_	10	_	-	-	13				15		1-	┦────
		1											1 10	_r
C,		-	10	-	10	-	10	1 -	10	1 -	10	-	10	pF
					1			<u> </u>				<u> </u>		+
					1.									
Co		-	20		20	-	20		20	-	20	-	20	pF
							1							
	трнг тргг тргн ттгн ттнг Сі	tpLH 2 tpHL 6 tpHL 6 tpLH 4.5 tpHL 6 tpLZ 6 tpZH 2 tpZH 4.5 6 2 true 6 C1 2	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$											

SWITCHING CHARACTERISTICS (V_{cc} = 5 V, T_A = 25°C, Input t_r, t_r = 6 ns) — HC/HCT356

	CL	CYMPOL	ТҮР	ICAL	UNITS	
CHARACTERISTIC	(pF)	SYMBOL	54/74HC	54/74HCT		
Propagation Delay CP \rightarrow Y, \overline{Y}	15	t _{PLH} , t _{PHL}	22	22	ns	
$Sn \rightarrow Y, \overline{Y}$	15	tplin, tphi	22	25	ns	
$\overline{LE} \rightarrow Y, \overline{Y}$	15	t _{PLH} , t _{PHL}	24	25	ns	
Output Disabling Time	15	tplz, tphz	13	13, 15	ns	
Output Enabling Time	15	tezl, tezh	12, 13	14	ns	
Power Dissipation Capacitance*		CPD	51	52	pF	

*CPD is used to determine the dynamic power consumption, per device

 $P_D = V_{CC}^2 f_1(C_{PD} + C_L)$ where:

f_i = input frequency.

C_L = output load capacitance.

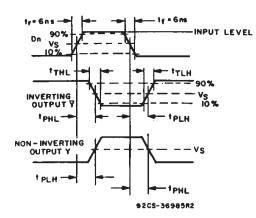
Vcc = supply voltage.

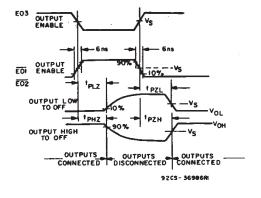
PREREQUISITE FOR SWITCHING FUNCTION - HC/HCT356

			:.	25	°C		-4	0°C t	o +85°	C	-5	5°C to	+125	°C	
CHARACTERISTIC	SYMBOL	Vcc	H	IC	H	CT	74	НС	74	ICT	54	HC	54ł	ICT	UNITS
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
CP Pulse Width		2	80	-	—	_	100	-	_		120	1_	1 —	_	
	t _{PLH}	4.5	16	-	20		20	-	25	_	24	-	30	-	ns
	t _{PHL}	6	14		<u> </u>	-	17			_	20	_			
LE Pulse Width		2	80	_			100	_	_	_	120	-	_	-	
	t _{PLH}	4.5	16	-	20	_	20	_	25		24	-	30	_	ns
	t _{PHL}	6	14	-			17	_	_		20		_		
Set Up Times		2	5		_		5	_	—		5	- 1		-	
Dn 🔶 CP	t _{su}	4.5	5		7	_	5	_	9	—	5	-	11	-	ns
		6	5	—	_		5	_		_	5		_	_	
		2	5	—		_	5	_	_	_	5			_	
Sn → LE	t _{su}	4.5	5		7	_	5	_	9	_	5		11		ns
		6	5		—	<u> </u>	5	_	_	_	5	-	_		
Hold Times		2	45		_		55			_	70		—	_	
Dn 🔶 CP	tn	4.5	9	_	9	_	.11		11	_	14	-	14		ns
···		6	8	_	—	_	9	_	_		12	_			
		2	60	-	_		75		_	_	90	—	_	_	
Sn 🔶 LE	tn	4.5	12		12		15	-	15		18	_	18	_	ns
		6	10		-		13	-	_	_	15	-			

SWITCHING CHARACTERISTICS (CL - 50 pF, Input tr, tr = 6 ns) --- HC/HCT356

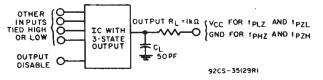
		25°C					IO° C t	o +85°	°C	-5															
SYMBOL	Vcc	Н	IC		СТ	74	нс	74	ют	54	нс	54H	ют	UNITS											
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.												
	2	-	255	_	-	—	320		-		385	-	-												
	4.5	-	51	-	51	—	64	-	64		77	—	77	ns											
Срнс	6		43	—		—	54			_	65	—	-												
	2	-	260	·		_	325	-	- 1	—	390		-												
-	4.5	-	52		59	-	65	_	74	_	78		89	ns											
LEHL	6	-	44				55	-	-	_	66	_	—												
	2	-	290	-	·	-	365	-	_	_	435	—	-												
	4.5	-	58		63		73	-	79		87		94	ns											
LDHL	6	_	49		-	—	62	-			74		-												
		-	155	-	-	—	195	—	_	—	235	-	—												
	2		31	—	33		39		41	-	47	-	50												
t _{PLZ}			26			_	33	_		_	40	_		ns											
t _{РНZ}		-	155	—			195	-			235		—	115											
	0	-	31	—	37	—	39	-	46	-	47	-	56												
			26		-	_	33	—	-		40		_												
	0	-	150	—	-		190		-		225	-	-												
		0	2	0	0	0	2	0	2	2	2	2	2	-	30	—	34	_	38	-	43	-	45	-	51
t _{PZL}			26	—	-	—	33		-		38	—		ns											
t _{PZH}		· <u> </u>	160	_	—	_	200	—	—	_	240	-	—	115											
	0	-	32	—	34		40	—	43		48		51												
			27	_	_	—	34	—	—		41		L												
tru	trus	-	-	1 1		-	—	75		-		90		-											
	4.5	-	12		12	—	15	-	15		18	-	18	ns											
THE	6	<u> </u>	10		L —		13		_		15	·	_												
C,			10		10		10		10		10		10	pF											
Co			20		20	•	20	_	20		20	_	20	рF											
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	54/74HC	54/74HCT
Input Level	V _{cc}	3 V
Vs	50% V _{cc}	1.3 V

Fig. 1 — Transition times and propagation delay times.





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